SSM&P Docket No.: 16818

IBM Docket No.: YOR920030293US1

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which THIN BURIED OXIDES BY LOW-DOSE OXYGEN IMPLANTATION INTO MODIFIED SILICON

the specification of which (che	eck one)			
x is attached hereto.				
was filed on	as United States App	lication Number		
or PCT International Ap	plication Number			
and was amended on	(if applic	able)		
I hereby state that I have revi the claims, as amended by any a	ewed and understand the conternation .	nts of the above identified specifi	ication, includ	ding
I acknowledge the duty to disclos with Title 37, Code of Federal	e information which is material Regulations, Section 1.56.	to the patentability of this applica	ation in accord	BRC
any foreign application for pate before that of the application	entor's Certificate, or '365(a) the United States, listed below the or inventor's certificate of	ed States Code, '119(a)-(d) or '365 of any PCT International application wand have also identified below, by or PCT International application, he	on which designa	atec
Prior Foreign Application(s)			Priority Clai	.med
(Number)	(Country)	(Day/Month/Year Filed)		No
(Number)	(Country)	(Day/Month/Year Filed)	Yes	No
I hereby claim the benefit unde	r 35 U.S.C. '119(e) of any Uni	ted States provisional application	(a) listed bel	ow.
(Application Number)	(Filing Date)			
(Application Number)	(Filing Date)			
of this application is not disclose the first paragraph of 35 U.S.	sed in the prior United States, o Sed in the prior United States, o C. '112, I acknowledge the duty n 37 CFR '1.56 which occurred b	es Application(s), or '165(c) of any insofar as the subject matter of expression in the property of the price	ach of the class he manner provi	ims ided

(Application Serial No.)(Filing Date)(Status) (patented, pending, abandoned)(Application Serial No.)(Filing Date)(Status) (patented, pending, abandoned)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: As a named inventor I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number).

Richard M. Ludwin (Reg. 33,010), Kevin M. Jordan (Reg. 40,277), Christopher A. Hughes (Reg. 26,914), John E. Hoel (Reg. 26,279), Joseph C. Redmond, Jr. (Reg. 18,753), Douglas W. Cameron (Reg. 31,596), Wan Yee Cheung (Reg. 42,410),

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Thu Ann Dang (Reg. 41,544), Louis F. Herzberg (Reg. 41,500), Derek S. Jennings (Reg. 41,473), Stephen C. Kaufman (Reg. 29, 551), Daniel P. Morris (Reg. 32,053), Aliaon D. Mortinger (Reg. 39,306), Louis J. Percello (Reg. 33,206), Robert M. Trepp (Reg. 25,933), Gali H. Zarick (Reg. 43,303), Rafael A. Perez-Pineiro (Reg. 46,041).

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

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Full name of fourth inventor		
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United States of America		
Citizenship		
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the specification of which (check one)			
x is attached herato.			
was filed on	as United States Applicati	on Number	
or PCT International Application	Number .		
and was amended on	(if applicable)		
I hereby state that I have reviewed and the claims, as amended by any amendment	referred to above.		
I acknowledge the duty to disclose info necordance with Title 37. Code of Foder	rmation which is material t al Regulations, Section 1.5	to the patentability of this a i6.	pplication in
I hereby claim foreign priority benefit foreign application(s) for patent or in which designated at least one country o by checking the box, any foreign applic application, having a filing date befor	ventor's dertificate, or §3 ther than the United States ation for patent or invento	65(a) of any PCT Internationa ;, listed below and have also or's certificate, or PCT Inter	l application identified below.
Prior Foreign Application(s)			Priority Claimed
	44	(Doy/Month/Year Piled)	Yes No
(Number)	(Country)	(Day/Month/Year Piled)	Yes No
I hereby claim the benefit under 35 U.S	.C. §119(a) of any Doited 8	tates provisional application	(s) listed below.
(Application Number)	Filing Date)		
(Application Number)	Filing Date)		
I hereby claim the benefit under 35 U.S International application designating to of the claims of this application is not in the manner provided by the first parameterial to the patentability of this all date of the prior application and the manner application applic	he United States, listed be t disclosed in the prior Un agraph of 35 U.S.C. §112, I oblication as defined in 37	low and, insofar as the subje lited States, or PCT Internati acknowledge the duty to disc CPR \$1.55 which occurred bet	ct matter of each onal application lose information ween the filing
(Application Serial No.)	Filing Date)	(Status) (patented, pendin	ug, abandoned)
(Application Serial No.)	Filing Date)	(Status) (patented, pendin	g, abandoned)
I hereby declare that all statements mainformation and belief are believed to I that willful false statements and the I section 1001 of Title 18 of the United 6 of the application or any patent issued	be true; and further that t ike so made are punishable : States Code and that willfu	hese statements were made with by fine or imprisonment, or be	h the knowledge oth, under
POWER OF ATTORNEY: As a named inventor this application and transact all busine registration number).	I hereby appoint the followers in the Patent and Trade	wing attorney(s) and/or agent mark Office connected therewit	(s) to prosecute th (list name and
Richard M. Ludwin (Reg. 33,010), Kevin b Hoel (Reg. 26,279), Joseph C. Redmond, & 42,410), Thu Ann Dang (Reg. 41,544), Lou C. Kaufman (Reg. 29, 551), Daniel P. Mon (Reg. 33,206), Robert M. Trepp (Reg. 25,	7r. (Reg. 18,753), Douglas (nis P. Herzberg (Reg. 41,50) rris (Reg. 32,053). Alison (W. Cameron (Reg. 31,596), Wan 0), Derek S. Jennings (Reg. 41 D. Mortinger (Reg. 39,306), Lo	Yee Cheung (Reg. 1,473), Stephen

46,041).

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SSM&P Docket No.: 16818 IBM Docket No.: YOR920030293US1 Ryan M. Mitchell Full name of fourth inventor Inversor's Signature 67 Picnic Woods Road, Clintondale, New York 12515 Residence United States of America Citizenship Same as Residence Post Office Address Devendra K. Sadana Full name of fifth inventor 90 Sky Top Drive, Pleasantville, NY 10570 Residence United States of America Citizenship Same as Residence

Post Office Address

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION as a below named inventor, I hereby declare that:

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OW-DOSE OXYGEN IMPLANTATI			•
the specification of which (check	one)		
x is attached hereto.			•
x is attached hereto.	as United States Applic	SCION MANDER	
or FCT International Appli	cation Number		
or PCT International ver-	(if applicab)	le)	
and was amended on	,		insting including
I hereby state that I have review	ed and understand the contents	s of the above identified specif	icalion, interest
I hereby state that I have review the claims, as amended by any amen	ndment referred to above.	· · · · · · · · · · · · · · · · · · ·	application in
I hereby state that I have any amente claims, as amended by any amente claims, as amended by any amente I acknowledge the duty to disclose of	e information which is materia	al to the patentability of this	~ K t
I acknowledge with Title 37. Code of accordance with Title 37. Code of I hereby claim foreign priority be foreign application(s) for patent which designated at least one coupling the box, any foreign application, having a filing date	penefits under Title 35, United or inventor's certificate, O	x \$365(a) of any PCT Internation ates, listed below and have also ates, listed below and have also	Priority Claimed
			Yes _ No
	(COURT DE)	(Day/Nonth/Year Filed)	хеа хо
		(Day/Nonth/1841)	
(Number)	(Country)	annisional applicati	on(s) listed below.
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(Application Number)	(Filing Date)		•
in a ma	(miliana Dota)		• •
(Application Number) I hereby claim the benefit under International application design of the claims of this application the manner provided by the finaterial to the patentability of date of the prior application as	nating the United States, list on is not disclosed in the pri- trat paragraph of 35 U.S.C. \$1 f this application as defined and the national or PCT interna-	12, I acknowledge the duty to di in 37 CFR \$1.56 which occurred I ational filing date of this appl	petween the filing ication:
	(Filing Date)	(Status) (patences, per	iting, water
(Application Serial No.)		(Status) (patented, per	nding, abandoned)
(Application Serial No.) Thereby declare that all state	ments made herein of my own to	nowledge are true and that all s	with the knowledge
Section 1001 of Title 18 of the	United States Code and that the issued thereon.	William Idiae Statement	TO TROSPORT
registration number).		following attorney(s) and/or ag Trademark Office connected the	ne ona) John R.
Hoel (Reg. 20,2131) Boseph T.	TAN TANIA D Werzberg (Reg.	(7), Christopher A. Hughos (Reg. 31,596), ouglas W. Cameron (Reg. 31,596), 41,500), Derek S. Jennings (Reg. 41,500), Mortinger (Reg. 39,306) (Reg. 43,303), Rafael A. Perez	LOUIS J. Percello

PAGE.30

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